UC Berkeley

UC Berkeley Previously Published Works

Title

Organic covalent modification to improve thermoelectric properties of TaS2.

Permalink

https://escholarship.org/uc/item/43f2c009

Journal

Nature Communications, 13(1)

Authors

Wang, Shaozhi Yang, Xiao Hou, Lingxiang et al.

Publication Date

2022-07-29

DOI

10.1038/s41467-022-32058-w

Copyright Information

This work is made available under the terms of a Creative Commons Attribution License, available at https://creativecommons.org/licenses/by/4.0/

Peer reviewed

nature communications



Article

https://doi.org/10.1038/s41467-022-32058-w

Organic covalent modification to improve thermoelectric properties of TaS₂

Received: 16 July 2021

Accepted: 12 July 2022

Published online: 29 July 2022

Check for updates

Shaozhi Wang^{1,2,4}, Xiao Yang^{2,3,4}, Lingxiang Hou^{1,2}, Xueping Cui ¹□, Xinghua Zheng ^{© 2,3} ⊠ & Jian Zheng ^{© 1} ⊠

Organic semiconductors are attracting considerable attention as a new thermoelectric material because of their molecular diversity, non-toxicity and easy processing. The side chains which are introduced into two-dimensional (2D) transition metal dichalcogenides (TMDs) by covalent modification lead to a significant decrease in their thermal conductivity. Here, we describe a simple approach to preparing the side chains covalent modification TaS₂ (SCCM-TaS₂) organic/inorganic hybrid structures, which is a homogeneous and nondestructive technique that does not depend on defects and boundaries. Electrical conductivity of 3,401 S cm⁻¹ and a power factor of 0.34 mW m⁻¹ K⁻² are obtained for a hybrid material of SCCM-TaS₂, with an in-plane thermal conductivity of 4.0 W m⁻¹ K⁻¹, which is 7 times smaller than the thermal conductivity of the pristine TaS₂ crystal. The power factor and low thermal conductivity contribute to a thermoelectric figure of merit (ZT) of ~0.04 at 443 K.

Thermoelectric (TE) devices can directly convert heat to electricity without moving parts or working fluids¹, which provide an environmentally friendly route for power generation or refrigeration, and have thus attracted significant attention. Generally, the thermoelectric energy conversion efficiency is determined by the thermoelectric figure of merit (ZT), defined as ZT = $S^2 \sigma T/\kappa$, where S, σ and T represent the seebeck coefficient, electrical conductivity, absolute temperature respectively, and κ is the thermal conductivity that includes contributions from both phonons and electrons^{2,3}. The optimization of ZT is severely limited by the anti-correlation between those transport coefficients. Therefore, it is desirable for a TE material to have favorable electrical conductivity and low thermal conductivity^{4,5}. Organic semiconductors offer numerous advantages for thermoelectric applications, such as molecular diversity, large-area preparation, high flexibility, low weight, easy processing, material abundance and nontoxicity^{6,7}. Organic compounds rely on sp² hybrid carbon-carbon bonds to conduct electricity, and the light weight of carbon atoms is conducive to effective phonon transport, which makes them theoretically have higher electrical conductivity and thermal conductivity. But in fact, the thermal conductivity of organic compounds is relatively low, and the side chain is one of the main factors causing this phenomenon⁸⁻¹⁰.

Two-dimensional (2D) transition metal dichalcogenides (TMDs) have attracted considerable interest owing to their respectable carrier mobility, density of states and tunable bandgap¹¹. Although the electrical conductivity of TMDs material is very high, it is not suitable for thermoelectric applications because of its high thermal conductivity. If the side chains can be introduced into the interlayers of TMDs materials by organic covalent modification, we can reduce the thermal conductivity and obtain a satisfactory ZT value. It is very difficult to introduce enough side chains in the interlayer of TMDs materials. Most of the previous methods relied on boundaries or defects modification¹², and only a few methods can introduce substituents in the basal plane^{13,14}. These methods need to exfoliate the bulk single crystal into single layers for full reaction, which will damage the original large single crystal structure, produce small fragments and form grain boundaries in the crystal, thereby greatly reducing the carrier mobility. Therefore, it is of great significance to intercalate and covalently modify the inner layer of TMDs while maintaining its single crystal structure.

¹Beijing National Laboratory for Molecular Sciences, Key Laboratory of Organic Solids, Institute of Chemistry, Chinese Academy of Sciences, Beijing 100190, China. ²University of Chinese Academy of Sciences, Beijing 100049, China. ³Institute of Engineering Thermophysics, Chinese Academy of Sciences, Beijing 100190, China. ⁴These authors contributed equally: Shaozhi Wang, Xiao Yang. 🖂 e-mail: cuixueping@iccas.ac.cn; zhengxh@iet.cn; zhengjian@iccas.ac.cn

Here, we demonstrate a simple covalent modification strategy that does not depend on boundaries or defects. The single crystal used in the experiment is 2H-TaS2. The organic groups (tert-Butyl isocyanate) are covalently bonded to 2D TMDs single crystal (TaS₂) directly to form the side chains covalent modification organic/inorganic hybrid structure, referred to as SCCM-TaS₂. The method can be used to conduct organic covalent modification of layered bulk single crystals deep into the crystal lattices. It is a homogeneous and nondestructive covalent modification method, which has no boundaries and defects formation. The achieved organic/inorganic hybrid structures have good stability. The thermal conductivity was found to be significantly suppressed owing to the side chains effect, leading to a significant improvement of ZT at 443 K. In general, the organic hybrid technology with side chains can effectively enhance the phonon scattering and improve the ZT value of TMDs material. This strategy can be extended to other layered materials, such as Bi₂Se₃¹⁵, TiS₂¹⁶ and SnSe₂17.

Results and discussion

Preparation of SCCM-TaS₂

In this article, we conduct organic side chains covalent modification of 2H-TaS₂ crystals by reacting with isocyanates (Fig. 1). The TaS₂ crystals are difficult to react with other substances to form covalent bonds, because there are no dangling bonds and all chemical bonds are saturated in the TaS₂ crystals. Therefore, the TaS₂ crystals do not react with isocyanates directly. The electrochemical reduction was used to charge the TaS₂ crystals and activate the crystal lamellae. Additionally, the electron doping effect was used to increase the electron cloud density of sulfur atoms, which can enhance the nucleophilic ability, and make it easy for sulfur atoms to attack the carbon atom of isocyanates to form covalent bonds. The SCCM-TaS₂ hybrid structure was achieved by immersing the electrochemical reduction product in tert-Butyl isocyanate at room temperature.

Structural characterization

After organic side chains covalent modification, the interlayer distance of TaS $_2$ expanded obviously. Studies with X-ray diffraction (XRD) showed a 67% increase in the interlayer distance from TaS $_2$ to SCCM-TaS $_2$ hybrid structure (Fig. 2a). In order to eliminate the interference of interlayer distance expansion caused by lithium ions on the results, a control experiment was performed and the XRD test was carried out. The (002) facet of the TaS $_2$ crystals shifted slightly toward lower angles after reacting with lithium atoms. However, the (002) facet of the TaS $_2$ crystals shifted significantly toward lower angles after reacting with naphthyl isocyanate and octadecyl isocyanate, and the interlayer distance expanded from 6.03 Å 18 to 10.00 Å and 11.20 Å respectively (Supplementary Fig. 2). The results showed that the expansion of TaS $_2$ interlayer distance was mainly attributed to the intercalation of isocyanate molecules. In addition, the XRD results indicated that covalent modification mainly happened at the basal planes, because

there is a dramatic change in (002) facet. The full width at half maximum (FWHM) of the hybrid structure changed by 0.27° , 0.74° respectively, indicating that good crystallinity was retained in the SCCM-TaS₂ hybrid structure. Studies with cross-sectional transmission electron microscopy (TEM) also showed an increase in the interlayer distance from $6.03\,\text{Å}$ in TaS₂ (Fig. 2b) to $10.36\,\text{Å}$ in the SCCM-TaS₂ hybrid structure (Fig. 2c), which was consistent with the XRD studies (Fig. 2a). TEM images showed that the lamellar structure of SCCM-TaS₂ crystal remained intact after covalent modification, and the single crystal structure was almost the same as that in the original.

Covalent modification of the TaS_2 crystals after reacting with tert-Butyl isocyanate was confirmed by observing signals from S 2p and C 1s regions in X-ray photoelectron spectroscopy (XPS) at -162.0 eV and -288.8 eV, respectively (Fig. 3a, b and Supplementary Fig. 7b). XPS analysis also revealed that S 2p3/2 (161.1 eV) and S 2p1/2 (162.4 eV) peaks were assigned to be S^{2-} in TaS_2 crystals (Fig. 3a) 19 . In addition to the peaks of S 2p in Fig. 3a, two peaks were present at 163.6 eV and 162.6 eV in Fig. 3b. From XPS analysis, two peaks for the Ta 4f spectra have been observed, with Ta 4f7/2 (26.0 eV) and Ta 4f5/2 (28.0 eV) peaks being assigned to Ta^{4+} . However, signals from the Ta 4f regions after covalent modification remained virtually unchanged (25–29 eV) (Supplementary Fig. 7a). Therefore, XPS analysis indicated that the covalent modification site of the side chain is on the sulfur atom 14 .

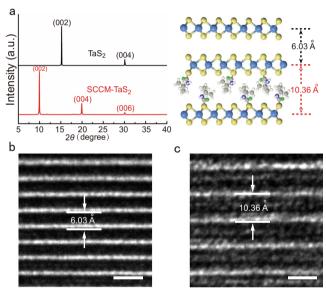


Fig. 2 | Structural characterization from the pristine TaS_2 and SCCM- TaS_2 hybrid structure. a XRD pattern and schematic of pristine TaS_2 single crystal and SCCM- TaS_2 hybrid structure. TEM characterization of TaS_2 single crystal (**b**) and SCCM- TaS_2 hybrid structure (**c**). (Scale bars, 1 nm).

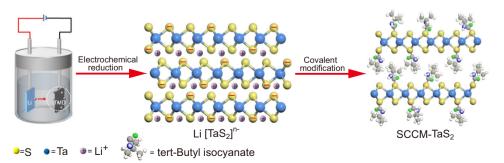


Fig. 1 | Schematic of synthesis processes of SCCM-TaS₂. Schematic of the electrochemical reaction and side chains covalent modification for SCCM-TaS₂ organic/inorganic hybrid structure.

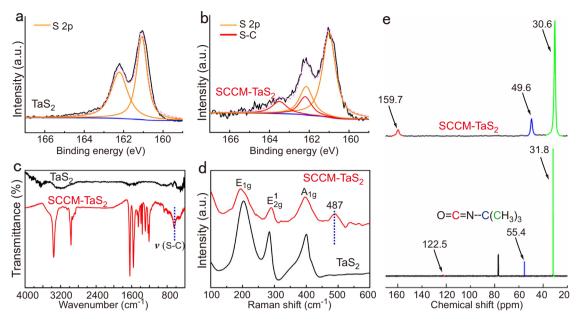


Fig. 3 | Chemical and spectral characterization from the pristine TaS₂ and SCCM-TaS₂ hybrid structure. XPS of S 2*p* regions from the pristine TaS₂ single crystals (**a**) and SCCM-TaS₂ hybrid structure (**b**). **c** FTIR spectrum of pristine TaS₂ single crystal and SCCM-TaS₂ hybrid structure. **d** Raman spectrum of pristine TaS₂

single crystal and SCCM-TaS₂ hybrid structure. **e** Liquid-state ¹³C NMR spectrum of tert-Butyl isocyanate (below) and solid-state ¹³C NMR spectrum of SCCM-TaS₂ hybrid structure (above).

Fourier transform infrared (FTIR) spectroscopy was used to study covalent modification of the TaS₂ crystals. The FTIR spectra of TaS₂ crystals and the SCCM-TaS₂ hybrid structure were shown in Fig. 3c. It can be seen that the SCCM-TaS₂ hybrid structure displayed strong signals at 1640 cm⁻¹, which were attributed to the carbonyl stretching vibration modes. The S-C stretching at 650 cm⁻¹ was also clearly observed²⁰. No signals from unreacted tert-Butyl isocyanate were detected, which ruled out the possibility of physical adsorption (Supplementary Fig. 4). FTIR analysis strongly suggested that the attachment of the functional groups is located on the chalcogen atoms. Figure 3d revealed the Raman spectroscopy of TaS2 and the SCCM-TaS₂ hybrid structure. The Raman peaks at the 400 cm⁻¹, 284 cm⁻¹ and $203 \, \text{cm}^{-1}$ for the pristine TaS_2 corresponded to the A_{1g} , E_{2g}^{-1} and E_{1g} modes, respectively¹⁹. The vibration peak at 487 cm⁻¹ in SCCM-TaS₂ hybrid structure indicated the existence of S-C bonds²¹. This result was consistent with that of FTIR, which verified the reaction sites of covalent modification. These obvious lattice vibration modes suggested that the TaS₂ crystals were highly crystalline even after modification.

To further elucidate the location of covalent modification sites on the TaS₂ crystals, we performed solid-state ¹³C NMR spectroscopy on the SCCM-TaS2 hybrid structure and obtained the chemical shifts of different kinds of carbon atoms. The spectrum was referenced with an external adamantane standard in which the peak at higher chemical shift was set at 38.43 ppm. As shown in Fig. 3e, the liquid-13C NMR spectroscopy of tert-Butyl isocyanate showed characteristic chemical shifts (δ) corresponding to carbonyl, tertiary and methyl carbons at 122.5 ppm, 55.4 ppm and 31.8 ppm, which were referenced with chloroform-d (CDCl₃) in which the peak at chemical shift was set at 77.0 ppm. The chemical shifts of tertiary carbon (δ 49.6 ppm) and methyl carbon (δ 30.6 ppm) in SCCM-TaS₂ hybrid structure changed slightly compared to that of tert-Butyl isocyanate precursor. The downfield shift of carbonyl carbon (δ 159.7 ppm)²² compared to that in the tert-Butyl isocyanate clearly indicated the presence of different carbon-heteroatom linkage, which stemmed from covalent modification. The results indicated that carbonyl carbons of tert-Butyl isocyanate were the main attachment sites of covalent modification.

Thermoelectric performance

Figure 4 showed the in-plane thermoelectric transport properties of 2H-TaS $_2$ crystal and SCCM-TaS $_2$ hybrid structure. The electrical parameters were measured by a four-probe method, which can eliminate the influence of contact resistance. The seebeck coefficient of 2H-TaS $_2$ at room temperature was about -7.6 ± 1.6 uV/K, which was consistent with that reported in the literatures 23,24 . After the side chains covalent modification of the TaS $_2$ crystals, the seebeck coefficient was -6.6 ± 0.3 uV/K and the electrical conductivity was $6100\,\mathrm{S\,cm^{-1}}$ at $-303\,\mathrm{K}$. In order to better understand the electronic transport in TaS $_2$ and SCCM-TaS $_2$ hybrid structure, temperature-dependent electrical conductivity and seebeck coefficient were plotted (Fig. 4a, b). As temperature increased, the electrical conductivity reduced and the absolute value of seebeck coefficient increased. These changes indicated that the material had typical degenerate semiconductor behavior 16.

At room temperature, the carrier concentration of TaS₂ single crystal and SCCM-TaS₂ hybrid structure are $1.79\times10^{22}\,\mathrm{cm}^{-3}$ and $5.72\times10^{22}\,\mathrm{cm}^{-3}$, respectively. The hall measurement showed that the carrier concentration significantly increased, which accounts well for the increase of electrical conductivity and reduction of seebeck coefficient. The in-plane mobility was calculated to be $0.67\,\mathrm{cm}^2\,V^{-1}\,\mathrm{s}^{-1}$ in the SCCM-TaS₂ hybrid structure, using μ = $\sigma/(nq)$, where μ , σ , n and q are mobility, electrical conductivity, carrier concentration and unit electron charge, respectively. The decrease of mobility from 1.40 cm² $V^{-1}\,\mathrm{s}^{-1}$ for the TaS₂ single crystal to $0.67\,\mathrm{cm}^2\,V^{-1}\,\mathrm{s}^{-1}$ for the SCCM-TaS₂ is due to the interaction between organic molecules and inorganic layers and the scattering of electrons at many interfaces²5.

Experimental measurement of thermal conductivity of 2D TMDs materials is still a challenging task. In this experiment, the thermal conductivity was measured with suspended micro bridge electrodes for small samples, which can eliminate the influence of substrate heat conduction $^{26-28}$. The in-plane thermal conductivity of the TaS $_2$ crystal and SCCM-TaS $_2$ hybrid structure were measured to be 28.5 W m $^{-1}$ K $^{-1}$ and 4.0 W m $^{-1}$ K $^{-1}$ at 443 K, respectively (Fig. 4c). Phonons and electrons collectively contributing to the thermal conductivity, after minus the electronic thermal conductivity estimated based on the

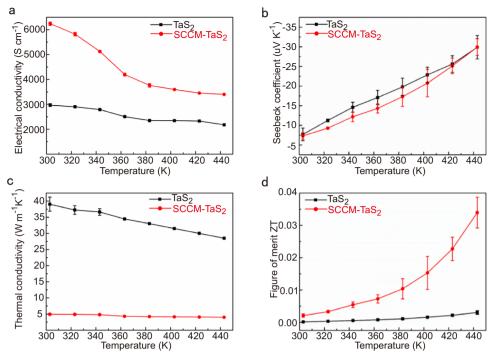


Fig. 4 | Thermoelectric properties of the pristine TaS_2 crystals and SCCM- TaS_2 hybrid structure. a Electrical conductivity. b Seebeck coefficient. c In-plane thermal conductivity. d In-plane thermoelectric figure of merit, ZT. All of the error bars

represent the standard deviation of the results obtained from independent measurements.

Wiedemann-Franz law ($\kappa_e = \sigma LT$)²⁹, the in-plane lattice thermal conductivity of the TaS₂ crystal and SCCM-TaS₂ hybrid structure were estimated to be 36 W m⁻¹ K⁻¹ and 0.6 W m⁻¹ K⁻¹ at 303 K, respectively. Due to the significant decrease of thermal conductivity, the in-plane ZT value of SCCM-TaS₂ hybrid structure is 10 times that of TaS₂ crystal, reaching -0.04 at -443 K.

The decrease of lattice thermal conductivity is due to the introduction of organic side chains through covalent bonds, which leads to the enhancement of phonon scattering. The covalent bonds between inorganic layer and organic layer are much stronger than van der Waals interaction. It is speculated that covalent bonds are more effective than van der Waals interaction in enhancing phonon scattering and reducing lattice thermal conductivity³⁰. In addition, the thermal conductivity decreased slightly with the increase of temperature (Fig. 4c). This is because when the thermal conductivity is dominated by anharmonic phonon-phonon interaction, the mean free path of phonon decreases with the increase of temperature³¹.

As the organic side chains were directly bonded to TMDs materials by covalent modification, the covalent bonds are stronger. Therefore, the products achieved by this method have higher thermal stability than that of the organic guest intercalated compounds by van der Waals¹⁶. We studied the thermal stability of the hybrid structure by thermogravimetric analysis (TGA). The traces of the first derivatives of the TGA traces showed that the decompositions of the functional groups occurred at 204 °C for SCCM-TaS₂ hybrid structure, which indicated the SCCM-TaS₂ hybrid structure had good thermal stability. TGA revealed that the degree of modification was up to 22.5 at.% relative to the TaS₂ which has been calculated by measuring the weight loss at 400 °C (Supplementary Fig. 3).

Discussion

In summary, we have successfully developed an effective strategy for organic side chains covalent modification of TMDs single crystal. The organic groups were covalently bonded to TMDs single crystal directly to form the side chains covalent modification hybrid structure with

superior crystallinity. After covalent modification, the thermal conductivity was reduced to one-seventh of the TaS_2 crystal, and the ZT value had been 10 times in the SCCM- TaS_2 hybrid structure than that in TaS_2 crystal. Tests showed the covalent hybrid structure had good thermal stability due to the existence of robust covalent bonds. This strategy of organic covalent modification can be extended to other layered materials and offers attractive platforms to obtain high ZT value thermoelectric devices.

Methods

Preparation of 2H-TaS₂ single crystal

 $2H\text{-}TaS_2$ was synthesized by heating stoichiometric ratios elements of Ta (99.99%, Alfa Aesar) and S (99.999%, Alfa Aesar) in an evacuated quartz tube at 900 °C for several days, followed by slowly cooling the quartz tube and its contents. The single crystal of $2H\text{-}TaS_2$ was grown by the standard chemical vapor transport method.

Preparation of SCCM-TaS₂

The TaS_2 single crystal and lithium foil were used as the cathode and anode in electrochemical reaction cells, the self-prepared solution was used as the electrolyte. As shown in Fig. 1, in the first step, the TaS_2 single crystal was charged by electrochemical reduction. In the second step, the electrochemical reduction products were immersed in tertbutyl isocyanate (98%), naphthyl isocyanate (99%), and octadecyl isocyanate (98%) for one week at room temperature. The products from these reactions were thoroughly washed with acetone before analysis.

Fabrication of devices

The nanosheets with the thickness of about 100 nm were obtained by mechanical exfoliation, and then transferred to the substrates or suspended microelectrodes. 100 nm of Au was deposited on the top of samples as electrodes with a shadow mask by vacuum thermal evaporation at a rate of about $0.3\,\text{Å}\,\text{s}^{-1}$. More details are described in the Supplementary Information.

Characterization

X-ray diffraction XRD was performed on a Panalytical-Empyrean. HR-TEM (JEOL JEM-2100F) was employed to image the samples. XPS was conducted using an ESCALab250-Xi electron spectrometer from VG Scientific with 300 W Al K α radiation. The IR spectroscopy was performed on a Bruker-Tensor-27. Raman was performed with a 532 nm laser under ambient conditions (in Via-Reflex). The solid-state NMR experiments were performed on a Bruker 400 MHz and the samples were carefully packed into a 3.2 mm zirconia rotor. Thermally evaporated 100 nm Au films were used as metal electrodes for electrical conductivity and seebeck coefficient measurement. Thermogravimetric analysis (TGA) was performed on a NETZSCH-STA 409 PC. TG analyzer equipped with thermal analysis controller. More details are described in the Supplementary Information.

Reporting summary

Further information on research design is available in the Nature Research Reporting Summary linked to this article.

Data availability

The authors declare that the experimental data supporting the results of this study can be found in the paper and its Supplementary Information file. The detailed data for the study is available from the corresponding author upon request.

References

- He, J. & Tritt, T. M. Advances in thermoelectric materials research: Looking back and moving forward. Science 357, eaak9997 (2017).
- Goldsmid, H. J. Thermoelectric Refrigeration. (Plenum, New York. 1964).
- Snyder, G. J. & Toberer, E. S. Complex thermoelectric materials. Nat. Mater. 7, 105–114 (2008).
- Pei, Y. Z., Wang, H. & Snyder, G. J. Band engineering of thermoelectric materials. Adv. Mater. 24, 6125–6135 (2012).
- Sootsman, J. R., Chung, D. Y. & Kanatzidis, M. G. New and old concepts in thermoelectric materials. *Angew. Chem. Int. Ed.* 48, 8616–8639 (2009).
- Zhao, W. R., Ding, J. M., Zou, Y., Di, C. A. & Zhu, D. B. Chemical doping of organic semiconductors for thermoelectric applications. *Chem. Soc. Rev.* 49, 7210–7228 (2020).
- Kim, G. H., Shao, L., Zhang, K. & Pipe, K. P. Engineered doping of organic semiconductors for enhanced thermoelectric efficiency. *Nat. Mater.* 12, 719–723 (2013).
- 8. Yang, Y. Z., Liu, Z. T., Zhang, G. X., Zhang, X. S. & Zhang, D. Q. The effects of side chains on the charge mobilities and functionalities of semiconducting conjugated polymers beyond solubilities. *Adv. Mater.* **31**, 1903104 (2019).
- Klements, P. G. Theory of the a-plane thermal conductivity of graphite. J. Wide Bandgap Mater. 7, 332–339 (2000).
- Balandin, A. A. Thermal properties of graphene and nanostructured carbon materials. *Nat. Mater.* 10, 569–581 (2011).
- 11. Cui, X. P. et al. Rolling up transition metal dichalcogenide nanoscrolls via one drop of ethanol. *Nat. Commun.* **9**, 1301 (2018).
- Chou, S. S. et al. Ligand conjugation of chemically exfoliated MoS₂.
 J. Am. Chem. Soc. 135, 4584–4587 (2013).
- 13. Wang, C. et al. Monolayer atomic crystal molecular superlattices. *Nature* **555**, 231–236 (2018).
- Voiry, D. Covalent functionalization of monolayered transition metal dichalcogenides by phase engineering. *Nat. Chem.* 7, 45–49 (2015).
- Zong, P. A. et al. Fabrication and characterization of a hybrid Bi₂Se₃/ organic superlattice for thermoelectric energy conversion. Adv. Electron. Mater. 5, 1800842 (2019).

- Wan, C. L. et al. Flexible n-type thermoelectric materials by organic intercalation of layered transition metal dichalcogenide TiS₂. Nat. Mater. 14. 622–627 (2015).
- 17. Li, Z. J. et al. Molecule-confined engineering toward super-conductivity and ferromagnetism in two-dimensional superlattice. *J. Am. Chem. Soc.* **139**, 16398–16404 (2017).
- Gamble, F. R., Disalvo, F. J., Klemm, R. A. & Geballe, T. H. Superconductivity in layered structure organometallic crystals. Science 168, 568–570 (1970).
- Wu, J. J. et al. Acid-assisted exfoliation toward metallic subnanopore TaS₂ monolayer with high volumetric capacitance. *J. Am. Chem.* Soc. **140**, 493–498 (2018).
- Aynsley, E. E., Greenwood, N. N. & Sprague, M. J. The oxidation of potassium selenocyanate by iodine pentafluoride. *J. Chem. Soc.* 4, 704–708 (1964).
- 21. Socrates, G. Infrared and Raman Characteristic Group Frequencies: Tables and Charts (Wiley, New York, 2001).
- Wynne, J. H., Jensen, S. D. & Snow, A. W. Facile one-pot synthesis of S-alkyl thiocarbamates. J. Org. Chem. 68, 3733–3735 (2003).
- Zong, P. A. et al. Flexible Foil of Hybrid TaS₂/Organic Superlattice: Fabrication and Electrical Properties. Small 16, 1901901 (2020).
- 24. Liu, Y., Hu, Z. X., T, X., Eric, D. B. & C. P. Electrical and thermal transport in van der Waals magnets 2H-M_xTaS₂ (M=Mn, Co). *Phys. Rev. Res.* **4**, 013048 (2022).
- Sharp, J. W., Poon, S. J. & Goldsmid, H. J. Boundary scattering and the thermoelectric figure of merit. *Phys. Stat. Sol.* 187, 507–516 (2001).
- Yang, X. et al. Experimental Study on Thermal Conductivity and Rectification in Suspended Monolayer MoS₂. ACS Appl Mater. Interfaces 12, 28306–28312 (2020).
- Wang, H. et al. Experimental study of thermal rectification in suspended monolayer graphene. *Nat. Commun.* 8, 15843 (2017).
- Yang, X., Zheng, X. H., Zhang, T., Chen, H. S. & Liu, M. Int. J. Heat. Mass Transf. 170, 121013 (2021).
- Mehta, R. J. et al. A new class of doped nanobulk high-figure-of-merit thermoelectrics by scalable bottom-up assembly. *Nat. Mater.* 11, 233–240 (2012).
- Goldsmid, H. J. & Sharp, J. W. Estimation of the thermal band gap of a semiconductor from Seebeck measurements. *J. Electron. Mater.* 28, 869–872 (1999).
- Ziman, J. Electrons and Phonons: The Theory of Transport Phenomena in Solids (Clarendon Press, Oxford, 1996).

Acknowledgements

We acknowledge the financial support from the National Key Research and Development Program of China (grant no. 2017YF0204700), the Key Research Program of the Chinese Academy of Sciences (grant no. XDPB13), the National Natural Science Foundation of China (22175184, 22105207, 51976215), the Scientific Instrument Developing Project of the Chinese Academy of Sciences (YJKYYQ20200017& YZ201615). We thank Dr. Wenrui Zhao and Prof. Chong'an Di for their assistance with electrical measurements. We thank Prof. Jia Zhu for the discussion. We thank Dr. Ye Zou for the assistance with Hall measurement.

Author contributions

S.W. carried out the experiments, and analyzed the data. J.Z. designed the work, conceptualized the work, and analyzed the data. L.H. and X.C. helped with characterization experiments. X.Y. and X.Z. helped with the thermal conductivity measurements. S.W., X.C., and J.Z. wrote the manuscript. All the authors participated in discussions of the research.

Competing interests

The authors declare no competing interests.

Additional information

Supplementary information The online version contains supplementary material available at

https://doi.org/10.1038/s41467-022-32058-w.

Correspondence and requests for materials should be addressed to Xueping Cui, Xinghua Zheng or Jian Zheng.

Peer review information *Nature Communications* thanks Kunihito Koumoto and the other anonymous reviewer(s) for their contribution to the peer review of this work.

Reprints and permission information is available at http://www.nature.com/reprints

Publisher's note Springer Nature remains neutral with regard to jurisdictional claims in published maps and institutional affiliations.

Open Access This article is licensed under a Creative Commons Attribution 4.0 International License, which permits use, sharing, adaptation, distribution and reproduction in any medium or format, as long as you give appropriate credit to the original author(s) and the source, provide a link to the Creative Commons license, and indicate if changes were made. The images or other third party material in this article are included in the article's Creative Commons license, unless indicated otherwise in a credit line to the material. If material is not included in the article's Creative Commons license and your intended use is not permitted by statutory regulation or exceeds the permitted use, you will need to obtain permission directly from the copyright holder. To view a copy of this license, visit http://creativecommons.org/licenses/by/4.0/.

© The Author(s) 2022